## Fractional power-law susceptibility and speci cheat in low tem perature insulating state of $o-TaS_3$

K.Biljakovic<sup>1</sup>, M.Miljak<sup>1</sup>, D.Staresinic<sup>1</sup>, J.C.Lasjaunias<sup>2</sup>, P.Monceau<sup>2</sup>,

 ${\tt H}$  .  ${\tt B\, erger^{\,3}}$  and  ${\tt F}$  . Levy  $^3$ 

<sup>1</sup> Institute of Physics, Hr-10 001 Zagreb, P.O.B. 304, Croatia

<sup>2</sup> CRTBT-CNRS, 38042 G renoble Cedex 9, BP 166, France

<sup>2</sup> IPA, EPFL, 1015 Lausanne, Switzerland

PACS.71.45.Lr { Charge density wave system s. PACS.75.50.Lk { Spin glasses and other random m agnets.

A bstract. { M easurements of the m agnetic susceptibility and its anisotropy in the quasi-onedimensional system o-TaS<sub>3</sub> in its low -T charge density wave (CDW) ground state are reported. Both sets of data reveal below 40 K an extra param agnetic contribution obeying a power-law temperature dependence (T)=AT <sup>0:7</sup>. The fact that the extra term m easured previously in speci c heat in zero eld, ascribed to low energy CDW excitations, also follows a power law  $C_{LEE}$  (0,T)=CT<sup>0:3</sup>, strongly revives the case of random exchange spin chains. Introduced impurities (0.5% Nb) only increase the amplitude C, but do not change essentially the exponent. W ithin the two-level system (TLS) m odel, we estimate from the amplitudes A and C that there is one TLS with a spin s= 1/2 localized on the chain at the lattice site per cca 900 Ta atom s. W e discuss the possibility that it is the charge frozen within a soliton-network below the glass transition T<sub>g</sub> 40 K determ ined recently in this system.

The universality of the low -T therm alproperties of am orphous materials remains a striking and alm ost unexplained property. Thus below 1 K, glasses, polymers and am orphous materials exhibit a roughly linear in T extra-phononic contribution to the speci c heat  $C_p$ , which have commonly been described through the standard model of two-level systems (TLS) intrinsic to structural disorder [1]. However it was demonstrated that random ness can also be revealed in long range order (LRO) ground state. A new class of materials exhibiting low -T universal features of glasses are the quasione-dimensional conductors in the Peierls state characterized by a periodic lattice distortion accompanied by a charge density wave (CDW) [2]. The model H am iltonian derived by Fukuyama, Lee and Rice [3] comprises an elastic energy term indicating the ability of the CDW to be stretched or compressed by pinning centers competing with an impurity pinning energy term. The random ness of the CDW ground state is rejected in the existence of many metastable states and hence there is a strong similarity with the X-Y m agnet in a random eld.

The universality of the disorder property is revealed in an extra-phononic contribution to the speci c heat with a smooth variation  $C_p / T$  in various inorganic quasi-1D CDW compounds [4] with 0.2 < 0.8. The same kind of contribution has been also found in some organic quasi 1-d conductors exhibiting a SDW or a spin-Peierls ground state, with up to

c EDP Sciences

EUROPHYSICS LETTERS

1 [5]. For all these compounds the corresponding LEE excitations demonstrate very peculiar dynam ical properties which can be understood only if they are weakly coupled to the phonon bath, underlying a clear di erence from the case of conventional glasses [4,5]. In addition, very speci c features are found for the glass transition evidenced in the SDW state [6], as well as in the CDW state [7], demonstrating the essential role of the screening of the CDW deform ations by free carriers in the substantial changes in the DW ground state. From this point of view, it is very important to better identify the common m icroscopic origin of LEEs and m ore speci cally the basic characteristics of the topological disorder, which is naturally expected to be related to the DW superstructure.

The fractional-power dependence of  $C_p$  T is usually described through a singularity in the density of states n (E) =  $n_o$  E<sup>-1</sup>. The same density of state (DOS) can yield a singular T – dependence of the magnetic susceptibility, T<sup>-1</sup>. The rst experimental evidence of this kind of phenomenon has been found in complex salts of tetracyanoquinodimethane (TCNQ) by Bulaevskii et al. [8]. It has been attributed to the strong anisotropy of the electronic structure, which makes the magnetic exchange interaction 1-dimensional (with very weak magnetic interactions between chains) and leads to the singular DOS. In the approach based on the random exchange H eisenberg antiferrom agnetic chain (REHAC) model a phenomenological DOS has been used, with parameters  $n_0$  and taken from experiment. However, the necessity of a singular distribution of random exchange was disproved since even discrete distribution, as in a chain broken into segments or interrupted strands, yielded universal REHAC features [9]. A ltogether, a lot of theoretical work has been devoted to random 1-d magnetic systems (see references in [10] and [11]).

The CDW system which shows the largest LEE contribution to  $C_p$  am ong allDW system s [4,12] is o-TaS<sub>3</sub>. It exhibits a Peierls transition at  $T_p = 218$  K, below which a CDW develops and turns into a low-T insulating ground state [2]. The exponent 0.3 of  $C_{LEE}$  / T was low enough for investigation of the possible contribution of the corresponding DOS to the susceptibility as  $_{LEE}$  / T <sup>1</sup>. In order to establish the correspondence between the two therm odynam ic quantities, and add som e m ore inform ation of the low temperature state, we have perform ed m easurem ents of the susceptibility and of the susceptibility an isotropy in a wide T-range, from 4 K to 300 K.

M agnetic susceptibility was measured by the Faraday method and the susceptibility anisotropy by a homem ade highly sensitive quartz torquemagnetometer [13]. The sensitivity of measurement is about 10<sup>12</sup> emu/g { for a samplemass of 10 mg. The o-TaS<sub>3</sub> sample was mounted in a strain freemanner, without grease or glue, between two thin quartz plates held by a light quartz spring. Note that the sample used for magnetic measurements (m = 7 mg) was from the same batch as the sample used in the speci c heat experiment. It boks like a carpet consisting of a bunch of needles all grown in the same chain direction. The pair of crystal axes perpendicular to chains are most probably oriented at random since no anisotropy was observed in this plane in the whole T-range.

As seen in g.1, both measurements, (g.1a) and surprisingly (g.1b) reveal a relatively large low -T upturm. Judging from the similar T-dependence of and and from the fact that the absolute value of is up to about 10% of , seem s to show up via electron spin g-factor anisotropy. Inset in g.1a displays the correlation between and

, showing their proportionality in the whole T-range, which brings the veri cation that the assumed source of the anisotropy originates from the g-factor anisotropy. Furtherm ore, the absence of any break in the slope proves that the low-T upturn is caused by the same spin carrying m agnetic species; those also giving the intrinsic param agnetism dom inant above 40 K. This high temperature behaviour, unexpected for CDW form ation, will be discussed elsewhere.

2

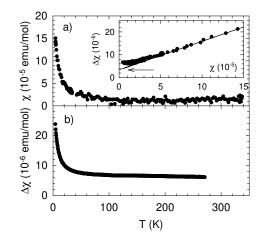


Fig. 1 { (a) and (b) versus temperature for  $o-TaS_3$  both show low -T uptum. The inset in (a) demonstrates the linear correlation between both sets of data and the possible estimation of the correction value indicated by the arrow.

It should be noticed that the small intercept on and/or axes for T ! 0 shows that either the corrections m ade to the m easured (tabulated Pascal constants) may not be correct, or som e T -independent contribution to is present. The importance of the proper correction is clearly demonstrated in g.2, which displays and versus tem perature in a log-log plot. It shows that both measurements can t the power law A  $T^{1}$ , but som e corrections should be made to achieve the same exponent  $(^{1})$ . The appropriate correcting values should be within the lim its of a given intercept on and/or axes displayed in the inset of g. 1a. One way is to subtract only the small intercept on the axis from the m easured anisotropy, i.e. -3.4 10<sup>6</sup> em u/m ole m arked by the arrow, what results both, in the linear correlation and the exponent 1 = -0.694 equal to that one of (-0.696).

There are a few important conclusions which can be drawn from these results. <u>First</u>, the fact that in this weak param agnetic m aterial also exhibits low temperature upturn, indicates the presence of the param agnetic \impurities" located on the lattice sites. O there ise, as in most cases when param agnetic impurities are at random, the contributions to the m easured

caused by the g-factor anisotropy in average would cancelout. Second, m easurem ents, beeing more sensitive, enable us to de nemore precisely the exponent 1 and also = the T-range of the power law t which rects the range of the exchange interaction J between localized magnetic species. In the absence of downwards deviation of the anisotropy from the power-law up to 30 K, we can estimate the lower limit of the corresponding magnetic interaction at low -T : JL 30-40 K [13]. Unfortunately, without the exact ESR g-factor m easurem ents cannot be used for the estimation of the number of param agnetic values "impurities" contained in the power law prefactor A. Third point is the estimation of the concentration of the param agnetic "in purifies". There are few approaches and regardless the applied model [10,13], the variation is within 50%. At this place, before entering a discussion about the origin of these magnetic species, we choose the extrem e case { "im purities" being

<sup>(</sup>l) In the course of the intrinsic susceptibility evaluation where relatively large low tem perature upturn has to be subtracted from the small susceptibility values, the choice of the subtracting procedure becomes delicate. We not that between the three possibilities of the low tem perature upturn description: the Curie law C  $T^1$ , the Curie-W eiss law and the A  $T^{-1}$  power law, the power law appears to be the most appropriate one.

EUROPHYSICS LETTERS

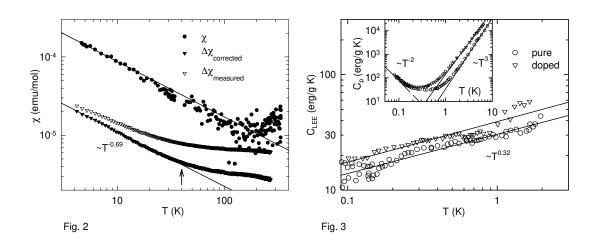


Fig.2 { Log-log plots of and versus T exhibit the same power-law dependence after the correction (explained in the text) is done. The arrow points to  $J T_q = 40 \text{ K}$  [8].

Fig.3 { Heat capacity of pure and N b-doped (0.5% nom in al) o-TaS<sub>3</sub> between 0.1K and 7K, analysed following eq. (1). In the inset is shown the total  $C_p$ . Main gure shows power law contributions of the LEEs obtained after subtraction of T<sup>2</sup> and  $C_1$  contributions.

free spins. By assuming a Curie law with a constant  $C_c = A = 4.310^{-4} K^{-0.3}$  emu/mol from (T < 4 K) data we obtain the spin concentration c= 1.15  $10^3$  mol  $^1$ . Within the purely 1-d

(I < 4 K) data we obtain the spin concentration  $c=1.15 \quad 10^{\circ} \text{ m ol}^{-1}$ . W this the purely I-d REHAC model, it yields linear concentration of 3.3  $10^{4}$  cm  $^{-1}$  per chain. It means that the spins of s=1/2 break the Ta-chain into segments of cca 900 Ta atom s.

The heat capacity was measured in a dilution refrigerator by means of a conventional heat-pulse transient technique [5,12]. When the regular phonon contribution, generally in T<sup>3</sup>, and a "hyper ne" contribution in T<sup>2</sup> are subtracted, an excess speci c heat remains below 1K the T-dependence of which shows a power law C T [12]. The total heat capacity for pure and Nb-doped o-TaS<sub>3</sub> samples is reported in inset of g. 3. Starting from a common low est-T hyper ne contribution  $C_h$  T<sup>2</sup>, the heat capacity of the doped sample shows a larger value in the upper T-range, in particular above T 2 K where  $C_p$  is dominated by the lattice contribution  $C_1$ . We believe that this enhancement is due to the strong defective e ect (point-defects) induced by the atom is substitution of the Ta atom sby lighter isoelectronic Nb atom s, which in particular results in variation of  $C_1$  (T) shower than cubic.

We analysed C<sub>p</sub> in the investigated T-range as the sum of three contributions. The two rst are originating from C<sub>LEE</sub> -decomposed into the hyper neterm C<sub>h</sub> T<sup>2</sup> and the power-law T [14] and the third one is of vibrational origin:

$$C_{p} = C_{h} \quad T^{2} + C \quad T + C_{l} \tag{1}$$

The parameters of ts for both curves are given in table I.

The main result of this analysis is the increase of the amplitude C of the power law contribution in the doped sample by cca 30%, whereas the exponent is preserved, as demonstrated in g.3. It is known from our previous work that the exponent in the power law contribution is a very speci c characteristics of the investigated CDW system [4], but it does not change for di erent sample batches or even for doping [15], hinting to an intrinsic property of each ground state. The same has been also found in REHAC system s with sim ilar consequences

4

Table I { Param eters of the  $\,$  ts of C  $_{\rm p}\,$  experim ental data to the eq. (1) for pure and 0.5% Nb-doped TaS3.

o–TaS₃	C <sub>h</sub> (erg K/g)	$C_1$ (erg/g K )	C (erg/g K <sup>1:32</sup> )		
pure	0.75	34 T <sup>3</sup>	30	0.32	0.02
Nb doped	0.75	140 T <sup>2:65</sup>	40	0.32	0.02

on doping [10] (note that we do not discuss the irradiation e ect).

As we noticed, this power law dependence of the speci c heat and m agnetic susceptibility can be treated through the phenom enological DOS,  $n(E) = n_0 E^{-1}$ , with two adjustable parameters. The calculation of the DOS depends slightly on the type of excitations and the di erence appears only in the amplitude  $n_0$ . In order to calculate the DOS of the LEE, we start with the hypothesis generally admitted [16] that CDW m etastable states correspond to TLS-type excitations rather than harm onic oscillators. Indeed the possibility of anharm onicity, in particular if the LEE are related to the pinning centers, is better described by the general anharm onic character of the double well potential of the TLS [17,18] in comparison to the single well harm onic potential. W ithin this frame, we have calculated the number of TLS

$$n = n (E) dE = 1:05 \quad 10^{4} \qquad E^{0:68} dE$$
(2)

n (E) expressed in units states/erg cm<sup>3</sup>, over the energy range 0.1 K to 40 K (note that  $E = 2.5 k_B T$  is the dom inant energy splitting contributing to  $C_p$  m easured at T). The upper lim it corresponds (for being consistent with the susceptibility) to the low-T m agnetic interaction  $J_L$  (=  $k_B T$ ) indicated in g.2. Therefrom we can get an estimation of the concentration of the LEE by comparison to N = 6.021  $1\hat{\theta}^3$  structural units de ned by the chemical form ula (with M = 277 g/m ol), being 1030 ppm (<sup>2</sup>), very close to the value 1150 ppm obtained from the susceptibility using Curie law! So, each TLS excitation is related to one spin s = 1/2.

W hat is the real nature of these excitations? O verall features resemble the widely investigated REHAC phenom enon with spin = 1/2 [8{10] demonstrating \standard" fractional-power law therm odynamical properties found in a wide family of organic charge transfer salts. Unfortunately, the nature of the elementary excitations of REHAC has not yet been elucidated, nor is it known what is their degree of localization and how it is related to the distribution of magnetic interaction [10]. In the following we intend to propose the realm icroscopic picture of these excitations in o-TaS<sub>3</sub>, to the best of our know ledge the rst inorganic system demonstrating REHAC properties.

We notice rst that o-TaS<sub>3</sub> exhibits very close exponents and , and even the same e ects on doping as REHAC, but the great di erence appears in the amplitudes of the investigated therm odynam ical properties and the corresponding number of param agnetic "in purities", as we provisionally named these low-energy elementary excitations. The REHAC contribution to the speci cheat ofm ostly investigated Q (TCNQ)<sub>2</sub> [10] is  $C_{spin} = 23.6 T^{0.18} m J/m o K$ , 30 times larger at 1 K than in o-TaS<sub>3</sub> (with comparable lattice contribution)! Sim ilarly, the estimated number of spins responsible for the low-T m agnetic properties was found to be in the range from 3% to 10% [9,10], m ore than 30 times larger than in o-TaS<sub>3</sub>! We might say that o-TaS<sub>3</sub> is an inorganic REHAC system in a highly \diluted" limit of param agnetic \in purities". Those

 $<sup>(^2)\</sup>ensuremath{\mathsf{For}}$  comparison, note that the integration up to E = 30 K yields a concentration of 920 ppm .

in purities are spins of s= 1/2 sparsely placed on the lattice sites cca every 900 Ta distances or 3000 A, interacting with  $J_L = 30-40$  K, which give rise to the typical REHAC behaviour.

The basic characteristics of REHAC – the disorder and localization – are inherent to the CDW ground state; so it is not surprising that both length scale and energy scale obtained from the REHAC behaviour are deeply related to the CDW ground state of o-TaS<sub>3</sub>. In fact for being m ore explicit, we believe that it is one additional manifestation of the change within the CDW ground state occurring at low –T.W e have recently demonstrated that the low temperature ground state of o-TaS<sub>3</sub> is reached through the glass transition on the level of the CDW superstructure [7]. We have related it to the freezing of dynam ics of CDW phase domains due to the C oulom b hardening in the absence of free carrier screening. The estim ate of the critical free carrier density  $n_e(T_g)$  which leads to freezing, to be about  $10^{15}$  e/cm<sup>3</sup>, is consistent with charge frozen at  $T_g$  as obtained from therm ally stim ulated discharge [19]. The corresponding volum e of 10<sup>15</sup> cm<sup>3</sup> per free carrier is close to the estim ates of the phase coherence volum e, and it m ight be at the origin of the twinkling domains seen in TEM [20] which have just the right size (4000 300  $300 \text{ A}^3$  4  $10^{16} \text{ cm}^3$ ).

Remaining degrees of freedom below  $T_g$  have been associated with topological defects of phase such as solitons, domain walls or dislocation bops. REHAC behaviour, which is essentially related to 1-dimensionality, can help in further understanding of LEE at low tem – peratures. Recent analysis of the properties of CDW in the low-T insulating phase [21] has shown that soliton-like defects on single chain, which perturb very weakly the phase on adjacent chains, can exist due to nonlinear screening. In typical conditions easily met in insulating CDW systems such solitons would change local value of electrochem ical potential allow ing creation of strongly 1-d metallic islands. Slight overlap of these islands can explain, for instance, enhanced conductivity observed (only) in the chain direction [22]. More important for us, these metallic islands can give localized unpaired spins leading to the REHAC behaviour due to the inherent strong anisotropy. We should add that this is not the single possible explanation, as there exist m ore exotic species of solitions that can have spin per se [23].

There should exist some netuning mechanism coming from the interaction with underlying lattice responsible for so speci c positions of the REHAC excitations. A strong in uence of the CDW on the lattice has been demonstrated in o-TaS<sub>3</sub> [24]. The glass transition itself leaves some ngerprints on the phonon dynam ics [25]. STM studies showed, that in addition to very complicated structure of o-TaS $_3$ , there are two CDW  $\,$  maxim a per unit cellalong the b $_0$ direction which are strongly correlated, so that they respond with a single Peierls transition. A sthere is no chain staggering, the CDW maxim a are adjacent to each other and the Coulom b repulsion encourages the uniform distribution of the CDW within the unit cell (i.e. they are not localized on any particular chains) [26]. It is very probable that the origin of the preferred position of the REHAC elementary excitation are the CDW dynamical defects, as sudden sliding of CDW for one lattice spacing in the chain direction has been observed even at room T [26]. In this very delicate entanglement of the lattice and CDW (s), it might be that the lattice tries to stagger the chains in order to reduce the Coulom b repulsion. On approaching the glass transition the Coulomb hardening of the CDW forces the CDW wave vector to t the commensurate value  $q_{2k_{F}} = 1/4 c_{0}$ . Hence, the solitons, being the defects of the CDW superstructure, tend to have preferential positions. Finally, also the structural defects m ight be dragged by the CDW and frozen together on the edges of the Lee-Rice domains, consistent with our previous discussion.

In conclusion, we would like to stress the importance of the detailed speci cation of low -T CDW excitations yielding the characteristic REHAC behaviour, equally from the experim ental point of view, as well as theoretical one. Charge-spin m ixing properties are essentially important as it is known that in CDW the soliton generates a localized region of a SDW and

6

a net spin (and vice versa) [23]. The problem of various kinds of solitons, self trapping and/or self doping seems to be a central point. Some further comparison with "classical" REHAC behaviour, especially concerning the dynam ical manifestations, m ight give some answers on the relevance of the lengths of correlations (LRO/SRO) in the corresponding ground states.

## REFERENCES

- Phillips W. A. (Editor), Am orphous Solids, Low Temperature Properties (Springer Verlag, Berlin) 1981; Hunklinger S. and RaychaudhariA.K., Progress in Low Temperature Physics, edited by D. F. Brewer, Vol. IX (Elsevier, New York) 1986, p. 265.
- [2] M onceau P., Electronic properties of Inorganic Q uasi O ne-D im ensional C om pounds, edited by P.M onceau (Reidel, D ordrecht) 1985, p.; G runer G., Density W aves in Solids (Addison-W esley C om p., Reading) 1994.
- [3] Fukuyama H. and Lee P.A., Phys. Rev. B, 17 (1978) 535; Lee P.A. and Rice T.M., Phys. Rev. B, 19 (1979) 3970.
- [4] Lasjaunias J.C., Biljakovic K. and Monceau P., Physica B, 165& 166 (1990) 893; Odin J. et al., Eur. Phys. J. B, 24 (2001) 315.
- [5] Lasjaunias J.C. et al, J. Phys.: Condens. M atter, 14 (2002) 837; Lasjaunias J.C. et al, J. Phys.: Condens. M atter, 14 (2002) 8583.
- [6] Lasjaunias J.C. et al, Phys. Rev. Lett., 72 (1994) 1283.
- [7] Staresinic D. et al, Phys. Rev. B, 65 (2002) 165109.
- [8] BulaevskiiL.N.etal, Sov.Phys.JETP, 35 (1972) 384.
- Bondeson C.R. and Soos Z.G., Phys. Rev. B, 22 (1980) 1793; Soos Z.G. and Bondeson C.R., Solid State Commun., 35 (1980) 11.
- [10] Clark W. G., Physics in One D imension, Solid State Sci., Vol. 23, edited by J. Bernasconi and T. Schneider (Springer Verlag, Berlin) 1981, p. 289 and references therein.
- [11] Fisher D.S., Phys. Rev. B, 50 (1994) 3799.
- [12] Biljakovic K., Lasjaunias J.C., Monceau P. and Levy F., Europhys. Lett., 8 (1989) 771.
- [13] M iljak M ., Cooper J.R. and Bechgaard K ., J. de Phys. C 3, 44 (1983) 893 and references therein.
- [14] Lasjaunias J.C. et al, Eur. Phys. J.B, 7 (1999) 541.
- [15] Biljakovic K., Lasjaunias J.C. and Monceau P., Synth. Metals, 29 (1989) F289.
- [16] Feigelman M.V. and Vinokur V.M., J. Phys. (France), 51 (1990) 409.
- [17] Klinger M. I., Phys. Reports, 165 (1988) 275.
- [18] Ovchinnikov Yu.N. et al, Europhys. Lett., 34 (1996) 645.
- [19] Staresinic D. et al, Synth. M etals, 103 (1999) 2130.
- [20] Chen C.H. and Fleming R.M., Solid State Commun., 48 (1983) 777.
- [21] Artemenko S.N. and Gleisberg F., Phys. Rev. Lett., 75 (1995) 497.
- [22] Takoshima T. et al, Solid State Commun., 35 (1980) 911; Zhilinskii S.K. et al, Zh. Eksp. Teor. Fiz., 85 (1983) 362; Sov. Phys. JETP, 58 (1983) 211.
- [23] Horow itz B., Phys. Rev. Lett., 48 (1982) 1416.
- [24] Golovnya A.V., Pokrovskii V.Ya. and Shadrin P.M., Phys. Rev. Lett., 88 (2002) 246401 and references therein.
- [25] Staresinic D. et al., Eur. Phys. J. B, 29 (2002) 71.
- [26] Gamie G. et al, Phys. Rev. B, 40 (1989) 11965